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Enhancing the performance of molecule-based piezoelectric sensors by optimizing their microstructures†

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By combining the rigidity of inorganic components with the flexibility of organic components, molecule-based ferroelectrics emerge as promising candidates for flexible, self-powered piezoelectric sensors. While it is well known that the performance of piezoelectric sensor devices depends not only on the materials' piezoelectric properties but also on the device architecture, research into enhancing molecule-based piezoelectric sensor performance through microstructure optimization has never been investigated. Here, we report the synthesis of a molecule-based ferroelectric, [(2-bromoethyl) trimethylammonium][GaBr₄] ([[(CH₃)₃NCH₂CH₂Br][GaBr₄]] (1), which exhibits a piezoelectric coefficient (d_{33}) of up to 331 pC N⁻¹. Our investigation reveals that the power density of a composite piezoelectric sensor device made from 1@S-PDMS(800#) (with microstructures) is twelve times that of 1-Flat-PDMS (without microstructures), due to a synergistic combination of piezoelectric and triboelectric effects. Interestingly, this flexible piezoelectric sensor can effectively detect human physiological signals, such as finger bending, breathing, and speech recognition, without the need for an external power supply.

Introduction

Piezoelectric sensors employ piezoelectric materials to transform mechanical energy into electrical energy.¹ These sensors are adept at detecting ambient pressure, strain, acceleration, and other environmental variables, converting these inputs into electrical signals.^{2–4} Consequently, their broad utility spans numerous fields, including industrial automation, automotive, and biomedical applications.^{5–9} Currently, the predominant materials used in wearable piezoelectric sensors are inorganic oxides and organic piezoelectrics.^{10–12} Inorganic piezoelectric materials typically achieve high levels of piezoelectric and electromechanical conversion; however, they are limited by their high stiffness and brittleness and the need for elevated processing temperatures.¹³ In contrast, organic piezoelectric materials, known for their high biocompatibility and low density, exhibit lower piezoelectricity.¹⁴ Consequently, the limitations of both inorganic and organic piezoelectric materials significantly restrict their use in wearable piezoelectric sensors.

Molecule-based ferroelectrics, composed of molecules or molecular ions connected through intermolecular forces such as van der Waals interactions and electrostatic attractions, offer advantages including structural diversity, chemical tunability, environmental friendliness, and low-temperature processing. These features not only enhance their biocompatibility but also facilitate seamless integration with other organic electronic technologies.^{15–19} Therefore, molecule-based ferroelectric materials are ideal candidates for constructing piezoelectric sensors, especially suited for self-powered biosensors.²⁰ Although recent years have seen significant progress in the synthesis of molecule-based ferroelectric materials, with some exhibiting piezoelectric properties comparable to those of traditional perovskite oxides,^{21–26} the development of piezoelectric sensors based on these materials is still in its infancy.²⁷ This is largely because the performance of piezoelectric sensors depends not only on the materials' piezoelectric properties^{28,29} but also on the architecture of the sensors themselves.³⁰ Surprisingly, current efforts to enhance the performance of piezoelectric sensors universally concentrate on improving the properties of molecule-based ferroelectric materials. In contrast, research into enhancing sensor performance by optimizing its microstructure remains largely unexplored. Here we report the synthesis of a molecule-based ferroelectric [(2-bromoethyl) trimethylammonium][GaBr₄] ([[(CH₃)₃NCH₂CH₂Br][GaBr₄]] (1), which exhibits a piezoelectric coefficient (d_{33}) of up to 331 pC N⁻¹. Significantly, the power density for the 1@S-PDMS(800#) device, created by embedding 1 into the pores of

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an S-PDMS(800#) film (S-PDMS(800#) = PDMS with a surface micropore structure by using P800 sandpaper as a template) is twelve times that of 1-Flat-PDMS, created by dispersing **1** within the Flat-PDMS film.

Results and discussion

Crystal structure

Compound **1** was synthesized through the reaction of 10 mmol $[(\text{CH}_3)_3\text{NCH}_2\text{CH}_2\text{Br}]\text{Br}$ and 5 mmol Ga_2O_3 in a HBr aqueous solution. The experimental powder X-ray diffraction (PXRD) patterns were in good agreement with the simulated patterns derived from the crystal structure at room temperature (Fig. S1†), confirming the purity of **1**. Thermogravimetric analysis (TGA) and differential thermal analysis (DTA) (Fig. S2†) measurements performed on powder samples revealed that melting of **1** commenced at 534 K (Fig. S3†). Single crystal structural analysis revealed that **1** crystallized in the orthorhombic polar space group $\text{Cmc}2_1$ at room temperature, with lattice parameters $a = 8.5264(3)$ Å, $b = 12.9009(3)$ Å, and $c = 13.4160(4)$ Å. The crystallographic data and refinement parameters are presented in Table S1.† The asymmetric unit of **1** comprises one $[(\text{CH}_3)_3\text{NCH}_2\text{CH}_2\text{Br}]^+$ cation and one $[\text{GaBr}_4]^-$ anion. The two carbon atoms on the side chain of the $[(\text{CH}_3)_3\text{NCH}_2\text{CH}_2\text{Br}]^+$ cations exhibited orientational disorder, presenting in two distinct positions (Fig. 1a). The 3D structure of **1** (Fig. 1b) is connected through electrostatic Coulomb forces between anions and cations, due to the absence of hydrogen-bonding and halogen-halogen interactions between adjacent $[\text{GaBr}_4]^-$ anions and $[(\text{CH}_3)_3\text{NCH}_2\text{CH}_2\text{Br}]^+$ cations (Fig. S4†). To further confirm that **1** crystallizes in the polar space group $\text{Cmc}2_1$, second harmonic generation (SHG) measurements were performed on a polycrystalline sample of **1**. The SHG intensity of the sample was approximately 1.36 times that of potassium dihydrogen phosphate (KDP) with equivalent particle sizes, further confirming its polar structure (Fig. S5†).

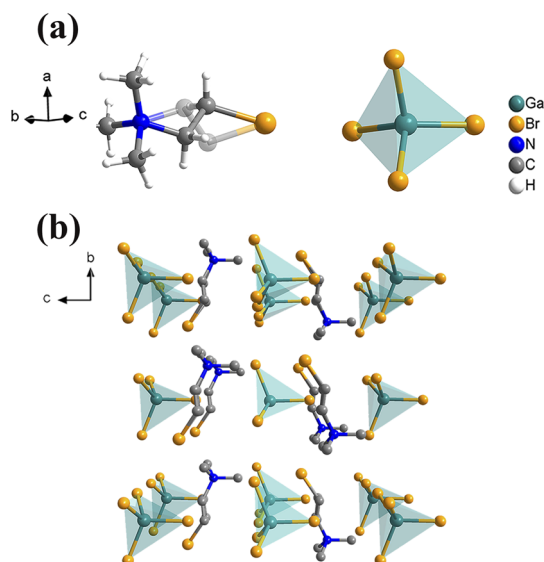


Fig. 1 (a) The asymmetric unit of **1**. (b) Unit cell of **1**.

Ferroelectric and piezoelectric properties

Fig. 2 shows the polarization–electric field (P – E) hysteresis loop measured using the polycrystalline film of **1** prepared by the drop-casting method. The saturated polarization (P_s) value of approximately $10.6 \mu\text{C cm}^{-2}$ closely approaches the theoretical value of $12.3 \mu\text{C cm}^{-2}$, as estimated using Gaussian 09 software at the B3LYP/def2TZVP level of theory based on the crystal structure of **1** (Table S2†). This P_s value is significantly higher than those reported for other molecule-based ferroelectrics, such as $\text{TMCM}_2\text{SnCl}_6$ ($8.7 \mu\text{C cm}^{-2}$),²² $[(\text{CH}_3)_3\text{NCH}_2\text{Cl}][\text{GaCl}_4]$ ($6.4 \mu\text{C cm}^{-2}$) and $\text{C}_6\text{H}_5\text{N}(\text{CH}_3)_3\text{CdBr}_2\text{Cl}_{0.75}\text{I}_{0.25}$ ($3.41 \mu\text{C cm}^{-2}$).^{25,26} Fig. S6† presents the d_{33} of a polycrystalline film of **1**, measured using a quasi-static method. The observed d_{33} value of 331 pC N^{-1} is comparable to those of high-performance piezoelectric inorganic oxide ceramics, such as PZT-4 (289 pC N^{-1}), $(\text{Ba}_{0.99}\text{Ca}_{0.01})(\text{Ti}_{0.98}\text{Zr}_{0.02})\text{O}_3$ (360 pC N^{-1}) and $(\text{Ba}_{0.85}\text{Ca}_{0.15})(\text{Zr}_{0.08}\text{Ti}_{0.92})\text{O}_3$ (365 pC N^{-1}).^{31,32} This comparison underscores the potential for practical applications of molecule-based ferroelectrics.

1@S-PDMS device manufacture

Given the excellent piezoelectric properties of **1**, piezoelectric energy harvesters based on this material were developed for energy collection applications. To enhance device performance, the microstructure of the piezoelectric energy harvester layer was optimized by introducing micropores through surface patterning using sandpaper. These micropores ensure uniform dispersion of **1** and reduce aggregation, thereby effectively decreasing the contribution of enhancement dielectric constants and Maxwell–Wagner–Sillars polarization to improve the piezoelectric response.^{33,34} Moreover, the deformability of the micropores enables **1** within them to undergo stress from multiple directions when compressed, potentially maximizing the piezoelectric effects from various directions.

Scheme 1 presents a diagram of the manufacturing process for the 1@S-PDMS composite film. The PDMS film was imprinted on sandpaper of varying roughness (P600, P800, P1200 and P1500) to create the PDMS film with a micropore pattern on the surface, namely, S-PDMS. An aqueous solution of **1** and isopropanol was alternately spin-coated onto S-PDMS. Isopropanol was used to remove excess piezoelectric **1**, ensuring its crystallization within the micropores on the S-PDMS surface. The resulting 1@S-PDMS composite film was

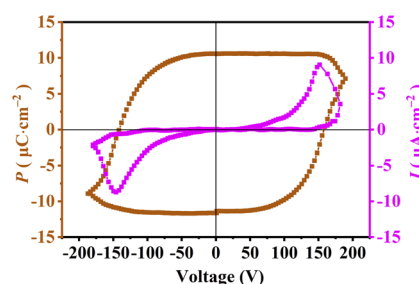
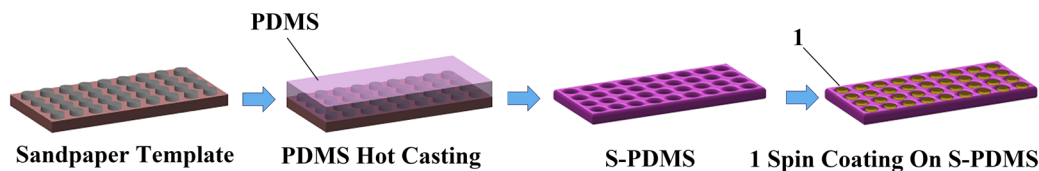


Fig. 2 Ferroelectric hysteresis loop of **1**.





Scheme 1 Schematic diagram of the 1@S-PDMS composite film manufacturing process.

then covered with electrodes made from flexible conductive tape composed of a polyester base metallized with copper and nickel and encapsulated with polyethylene terephthalate (PET) to complete the device assembly (Fig. S7†).

Fig. 3a displays the scanning electron microscope (SEM) image of S-PDMS, which was prepared using P800 sandpaper as the template, referred to as S-PDMS(800#). The average pore diameter is $18.25\ \mu\text{m}$ (Fig. 3b), closely aligning with the average particle size of P800 sandpaper, which is $18.75\ \mu\text{m}$ (Fig. S8†). Additionally, the average pore diameters of S-PDMS prepared with P600, P1200, and P1500 sandpaper templates are $24.69\ \mu\text{m}$, $12.94\ \mu\text{m}$, and $9.93\ \mu\text{m}$, respectively (Fig. S9†). Piezoelectric **1** was spin-coated onto S-PDMS substrates of varying micropore sizes. As depicted in Fig. 3c, most samples crystallized within the micropores without any noticeable aggregation. The XRD patterns of the 1@S-PDMS(800#) composite film (Fig. 3d) confirm the presence of crystalline **1** on the S-PDMS(800#) film. In contrast to the addition of isopropanol during film preparation (Fig. 3c), when isopropanol is not used, **1** not only crystallizes within the micropores but also forms substantial deposits on the film's surface (Fig. S10†).

Because the concentration of **1** in the composite film is a critical factor in device performance, the number of spin-coating cycles was utilized to regulate its content within the film. Fig. 4 displays the open-circuit voltage (V_{oc}) and short-circuit current (I_{sc}) of 1@S-PDMS(800#) across various spin coating cycles. These measurements were taken by applying a consistent pressure of approximately 20 N to their surfaces using palm pressure. When the spin-coating cycle is set to one, the V_{oc} is 50 V and the I_{sc} is $3.8\ \mu\text{A}$. As the spin-coating cycles increase to 3, 5, and 7, device performance improves. At 7 cycles,

V_{oc} and I_{sc} reach their peak values of 120 V and $25\ \mu\text{A}$, respectively. However, at 9 cycles, there is a decrease in device performance, with V_{oc} dropping to 75 V and I_{sc} to $20\ \mu\text{A}$. A similar trend in V_{oc} and I_{sc} was also observed in other devices, *i.e.*, 1@S-PDMS(600#), 1@S-PDMS(1200#) and 1@S-PDMS(1500#) (Fig. S11†). The optimal performance of the devices at seven spin-coating cycles can be attributed to the gradual increase in the content of **1** within the film as the number of cycles increases. However, when the spin-coating cycles exceed seven, despite the continuing increase in the content of **1**, it begins to aggregate, as illustrated in Fig S12.† This aggregation leads to enhanced dielectric constants and Maxwell–Wagner–Sillars polarization,^{33,34} and consequently, a high content of **1** would degrade rather than enhance the piezoelectric response.

For comparison, four devices with distinct structures but identical sizes to 1@S-PDMS were prepared, *i.e.*, (1) Flat-PDMS film, which lacks a micropore structure on its surface; (2) S-PDMS, featuring micropores on its surface; (3) 1-Flat-PDMS, where **1** is dispersed within the bulk of the Flat-PDMS film; and (4) 1-S-PDMS, where **1** is dispersed within the bulk of the S-PDMS film. The devices of each distinct structure with the best performance were chosen for comparison (under 20 N palm pressure) (Fig. S13†). As demonstrated in Fig. 5, the performance of S-PDMS, 1-Flat-PDMS and 1-S-PDMS is notably superior to that of Flat-PDMS, yet significantly inferior to that of 1@S-PDMS. Notably, S-PDMS exhibits a distinct output signal with a V_{oc} of 35 V and an I_{sc} of $5\ \mu\text{A}$, likely due to its unique surface structure. This structure features a layer of micropores between the electrodes, which introduces a triboelectric response.³⁵ Distinctly, the remarkable performance of 1@S-PDMS stems from the synergistic interplay between its piezoelectric and triboelectric responses (Fig. S14†).^{36,37} When **1** is embedded within the micropores on the surface of PDMS, rather than within its bulk, the surface microstructure facilitates uniform dispersion of **1** and prevents aggregation.

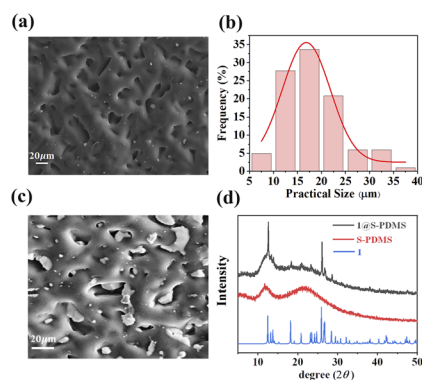


Fig. 3 (a) SEM image of S-PDMS(800#) with a micropore pattern on the surface. (b) Pore size distributions of S-PDMS(800#). (c) SEM image of 1@S-PDMS(800#). (d) The XRD patterns of **1** and 1@S-PDMS(800#).

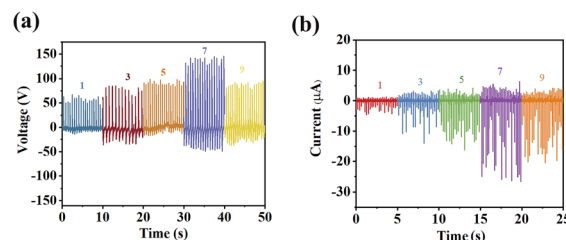


Fig. 4 V_{oc} (a) and I_{sc} (b) for 1@S-PDMS(800#) with different spin coating cycles with palm pressure.



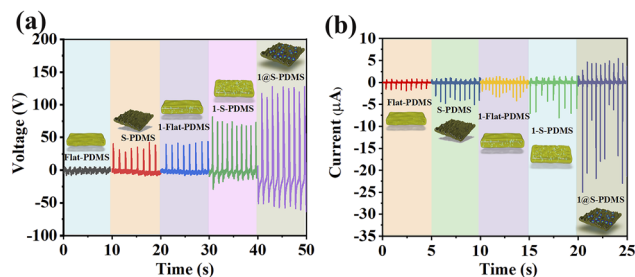


Fig. 5 V_{oc} (a) and I_{sc} (b) for various devices with different constructions at 20 N palm pressure.

Additionally, under mechanical pressure, **1** can easily induce piezoelectric charges on the surface of S-PDMS.³⁸

Given the critical importance of the surface microstructure, we conducted further investigations into the effects of surface microstructures with varying pore sizes on device performance. Comparing the optimal output performance of four types of **1@S-PDMS** devices with varying pore sizes (Fig. 6) (where the number of spin-coating cycles was maintained at seven as previously discussed and the pressure applied to the device was 20 N), the device of **1@S-PDMS(1500#)** exhibited the poorest performance. A clear trend emerged, showing enhanced performance with increasing pore sizes within S-PDMS. The device with a pore size of 800# (**1@S-PDMS(800#)**) delivered the best performance. However, further increasing the pore size beyond 800# led to a decline in performance. To elucidate this unique effect of pore size, the triboelectric performance of the S-PDMS blank across varying pore sizes was investigated. As shown in Fig. S15,† the triboelectric performance of the S-PDMS blank improves as the pore size increases, peaking when the pore size reaches 800#. And as the pore size continued to increase, the performance decreased. Typically, a decrease in micropore size typically leads to an increase in effective surface area, which in turn enhances device performance.³⁹ But the surface roughness is also a critical factor of triboelectricity. The improvement in the triboelectric performance of the S-PDMS blank as the pore size increases can be attributed to an increase in surface roughness.³⁵ Thus, the most optimal performance exhibited by **1@S-PDMS(800#)** is due to the synergistic interplay between piezoelectricity and triboelectricity.

Fig. S16† presents the power density for **1@S-PDMS(800#)** and **1-Flat-PDMS**. The power density for **1@S-PDMS(800#)**

peaks at approximately $490 \mu\text{W cm}^{-2}$ with a load resistance of $7 \text{ M}\Omega$, whereas **1-Flat-PDMS** achieves only a maximum of $41 \mu\text{W cm}^{-2}$. Because the maximum power density for **1@S-PDMS(800#)** is 12 times that of **1-Flat-PDMS**, this result clearly indicates that the device's microstructure plays a crucial role in enhancing its performance. It is worth mentioning that while the power density of **1@S-PDMS** is lower than that reported for the single crystal-array device of $\text{C}_6\text{H}_5\text{N}(\text{CH}_3)_3\text{-CdBr}_2\text{Cl}_{0.75}\text{I}_{0.25}\text{-PDMS}$ ($1100 \mu\text{W cm}^{-2}$)²⁶ and ultrasonic response power density of PVDF/TMCM-MnCl_3 ($1020 \mu\text{W cm}^{-2}$),⁴⁰ the power density of **1@S-PDMS(800#)** is not only comparable to that of $\text{V-NaNbO}_3\text{-PDMS}$ ($480 \mu\text{W cm}^{-2}$),⁴¹ but also surpasses the power densities of all reported molecule-based energy harvesting devices, such as $115 \mu\text{W cm}^{-2}$ of $\text{TMCMCdCl}_3\text{-PDMS}$ ³³ and $74 \mu\text{W cm}^{-2}$ of $\text{MASnBr}_3\text{-PDMS}$ (Table S3†).²⁰

Applications in human physiological signal monitoring

To assess the potential of **1@S-PDMS(800#)** as a flexible pressure sensor, the output signals of the sensor under various stresses (Fig. S17†) were performed. Based on these data, the sensor's sensitivity at various stress levels was obtained as shown in Fig. 7. The output voltage increases proportionally with stress up to 24 kPa, after which this trend slows down. Beyond 45 kPa, the output voltage remains essentially constant, likely due to the theoretical limitations of effective strain in piezoelectric materials at high pressure.^{42,43} According to the data in Fig. 7, the sensitivity of the sensor is 3.57 V kPa^{-1} below 24 kPa and 1.02 V kPa^{-1} in the range of 24 kPa to 45 kPa. Although this sensitivity is lower than the highest reported value for PVDF-based PVDF/TMCM-MnCl_3 (6.21 V kPa^{-1}),⁴⁰ it is still the second highest sensitivity reported for molecule-based sensors to date (Table S4†). The stability of the **1@S-PDMS(800#)** sensor was also evaluated under both low (10 kPa) and high (70 kPa) palm stresses (Fig. S18†). After hundreds or even thousands of cycles, the device shows no signs of performance degradation, indicating that the sensor exhibits excellent stability under both low and high stresses.

Given the excellent sensing properties of **1@S-PDMS(800#)**, it was employed to detect pressure signals generated by physiological processes in the human body. Fig. 8a illustrates that when the finger joint bends at angles of 45° and 90° , it produces

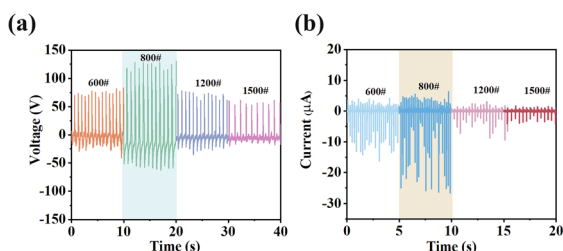


Fig. 6 V_{oc} (a) and I_{sc} (b) for **1@S-PDMS** with different micropore sizes.

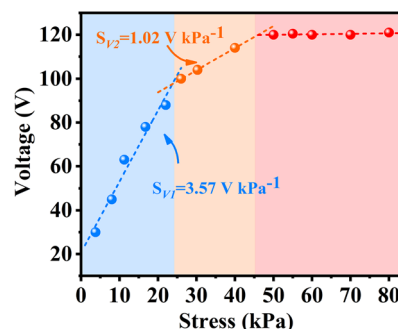


Fig. 7 The sensitivity of the sensor under various stresses.



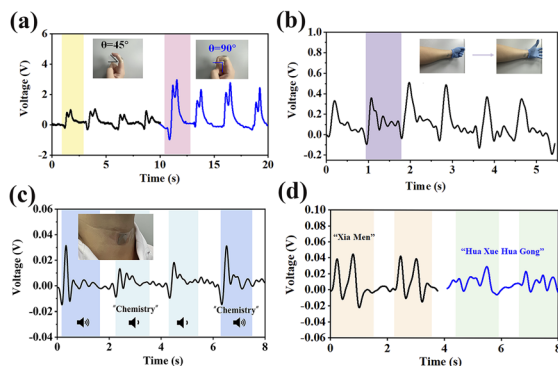


Fig. 8 (a) Signal from bending the knuckles. (b) Signal from clenching the palm. (c) Recognition of the word “chemistry” at different volumes. (d) Recognition of the Chinese words “Xia Men” and “Hua Xue Hua Gong”.

voltage peaks of up to 1.02 V and 2.94 V, respectively. When the finger joint is bent repeatedly four times, the sensor consistently delivers four sets of signals with identical waveforms and values, demonstrating the sensor's stable and reliable performance.³⁰ Similarly, we attach sensors to the wrist that can detect movements from clenching to opening of the palm (Fig. 8b). Fig. 8c and d illustrate speech signals originating from the movement of laryngeal muscles and the vibration of vocal cords. The signal shape remains consistent, demonstrating the sensor's robust performance. Even when the word is read at varying volumes, only the peak value of the signal fluctuates, while the waveforms stay unchanged. This highlights the sensor's ability to detect minute pressures from acoustic vibrations.⁴⁴ Furthermore, the sensor is capable of recognizing distinct words; for example, when pronouncing “Xia Men” and “Hua Xue Hua Gong”, the voltage waveforms exhibit double peaks and multiple sets of double peaks, respectively (Fig. 8d). Additionally, the sensor was placed inside a face mask to monitor the wearer's breathing rate, serving as a valuable tool for assessing health—a task that has become particularly important in the post-pandemic era. As shown in Fig. S19,[†] the average breathing rate of the subjects was 3.0 seconds, comfortably within the normal range of 3 to 5 seconds per breath. The voltage waveforms display excellent stability and clearly distinguish each breath, underscoring the sensor's capability to detect the frequency of weak signals from breathing.

Conclusions

In summary, we have developed a molecule-based ferroelectric **1**, with a piezoelectric constant d_{33} of 331 pC N⁻¹. Notably, the power density of the composite piezoelectric sensor device **1**@S-PDMS(800#) is twelve times that of **1**-Flat-PDMS, underscoring the critical role of microstructures in enhancing performance. This improvement is attributed to a synergistic combination of piezoelectric and triboelectric effects. As a flexible pressure sensor, **1**@S-PDMS(800#) effectively detects human physiological signals, such as finger bending, breathing, and speech

recognition, without the need for an external power supply. Given that the power density of **1**@S-PDMS(800#) surpasses the power densities of all reported molecule-based energy harvesting devices (excluding single-crystal array devices and ultrasound-driven PVDF/TMCM-MnCl₃ devices) and boasts the second highest sensitivity reported for molecule-based sensors to date, this work not only advances the practical applications of molecule-based piezoelectric materials but also explores their potential in self-powered sensing applications.

Experimental

Preparation

All the chemical solvents and reagents were employed without further purification. All spin-coating operations were conducted using a KW-4A spin coater from the Institute of Microelectronics, Chinese Academy of Sciences.

Initially, 5 mmol of gallium(III) oxide was dissolved in 40% HBr at 130 °C. Subsequently, 10 mmol of (2-bromoethyl) trimethylammonium bromide was added and dissolved *via* reflux condensation, resulting in a clear orange solution. After approximately one week of evaporation, orange block crystals of **1** were obtained, with a total yield of 92% based on (2-bromoethyl) trimethylammonium bromide. To produce a powdered form of **1**, the mixed solution was evaporated at 100 °C, and the resulting powder was washed three times with absolute ethanol.

Fabrication of sensor devices

The base polymer of PDMS (part A), curing agent (part B), and toluene were mixed in a 10 : 1 : 11 ratio and stirred to produce the PDMS solution. This solution was then evenly dispersed in either a Teflon evaporator or Teflon evaporator lined with sandpaper of varying coarseness (P600, P800, P1200, and P1500, where ‘P’ is the roughness class of sandpaper) on the bottom. The **1**@S-PDMS composite films were fabricated as follows: a 1 mol per L [(CH₃)₃NCH₂CH₂Br][GaBr₄] aqueous solution was prepared by dissolving 5 mmol of **1** in 5 mL of deionized water. S-PDMS was applied to the silicon substrate, and 100 μL of the [(CH₃)₃NCH₂CH₂Br][GaBr₄] solution was dispersed onto S-PDMS using a micropipette and spun at 1500 rpm for 30 seconds. Subsequently, 1 mL of isopropanol was added, and the sample was then spun at 2500 rpm for 1 minute. This spin-coating process was repeated for a varying number of cycles. Finally, S-PDMS was heated on a 100 °C hot plate for 1 hour to obtain **1**@S-PDMS.

For composite films with **1** dispersed in the bulk of PDMS, **1** was dispersed in the PDMS solutions at varying mass fractions, referred to as **1**-Flat-PDMS. Similarly, **1** was dispersed in S-PDMS, referred to as **1**-S-PDMS. The prepared solutions were evenly spread in a Teflon evaporator (diameter = 60 mm) and subsequently cured. All types of composite films were then covered with conductive tape on both the top and bottom surfaces, serving as electrodes in the fabricated sensor devices (the active areas are 2 × 2 cm²).



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